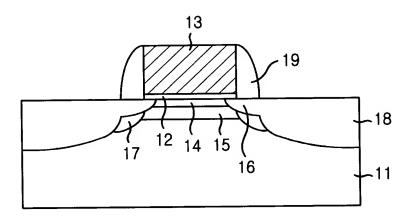
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FIG. 1 (PRIOR ART)



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FIG. 2A (PRIOR ART)

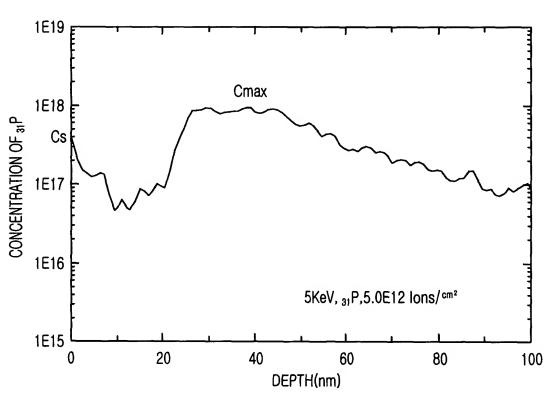
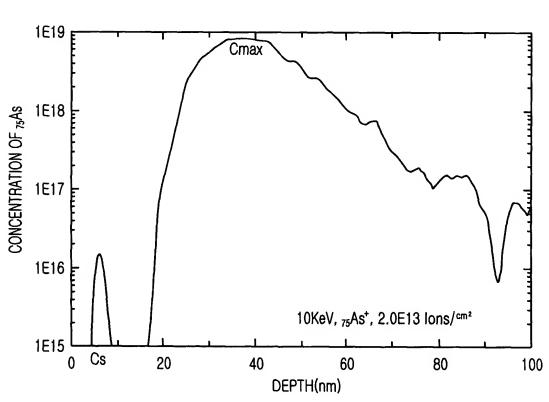
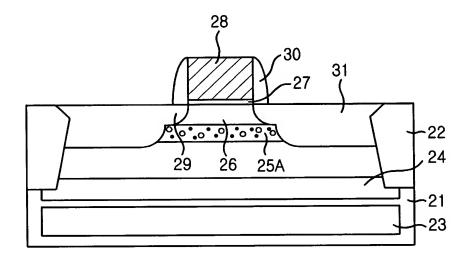


FIG. 2B (PRIOR ART)



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FIG. 3



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FIG. 4A

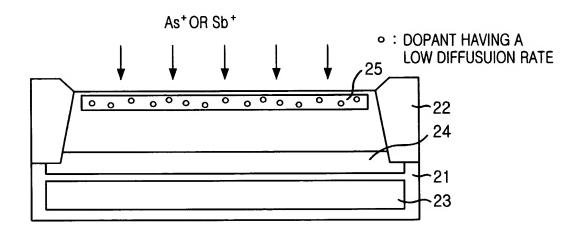
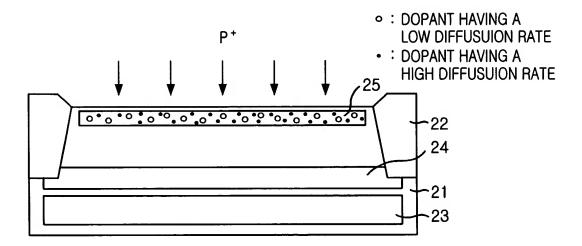


FIG. 4B



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FIG. 4C

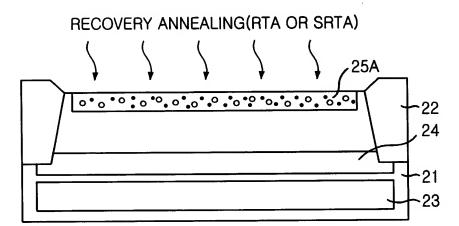
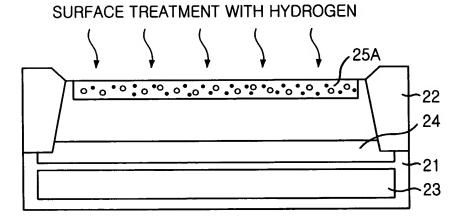


FIG. 4D



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FIG. 4E

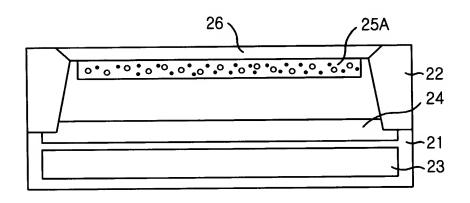
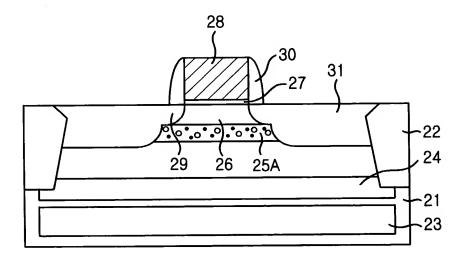
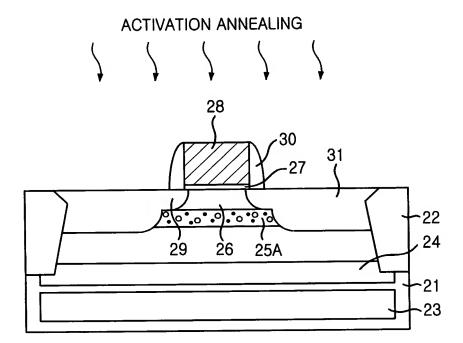


FIG. 4F



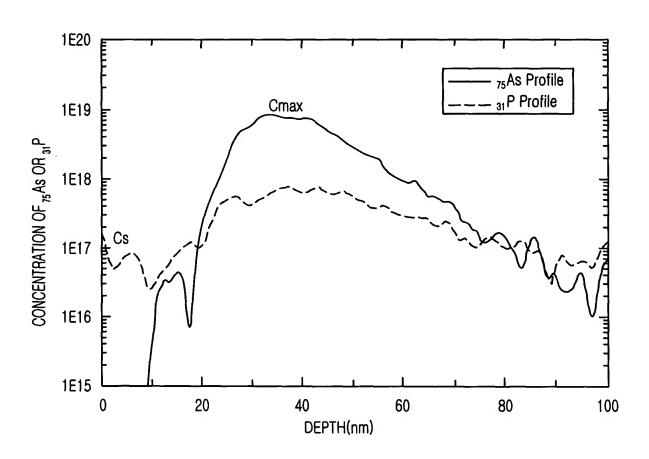
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FIG. 4G



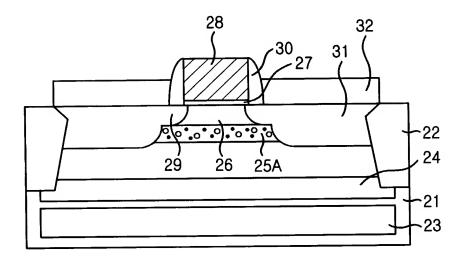
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FIG. 5



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FIG. 6



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FIG. 7

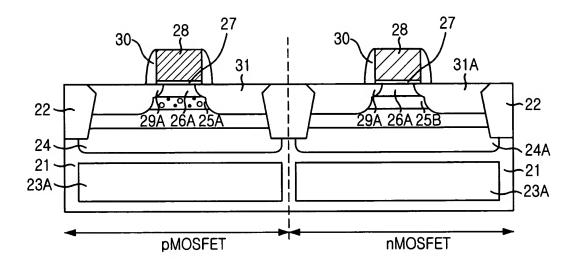


FIG. 8

